

# TC74HC138AP, TC74HC138AF, TC74HC138AFN

## 3 - TO - 8 LINE DECODER

The TC74HC138A is a high speed CMOS 3 - to - 8 DECODER fabricated with silicon gate C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

When the device is enabled, 3 Binary Select inputs (A, B and C) determine which one of the outputs ( $\bar{Y}0$  -  $\bar{Y}7$ ) will go low.

When enable input G1 is held low or either  $\bar{G}2A$  or  $\bar{G}2B$  is held high, decoding function is inhibited and all outputs go high.

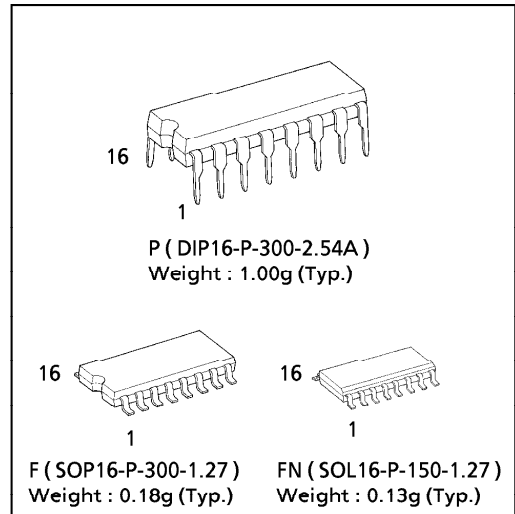
G1,  $\bar{G}2A$ , and  $\bar{G}2B$  inputs are provided to ease cascade connection and for use as an address decoder for memory systems.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

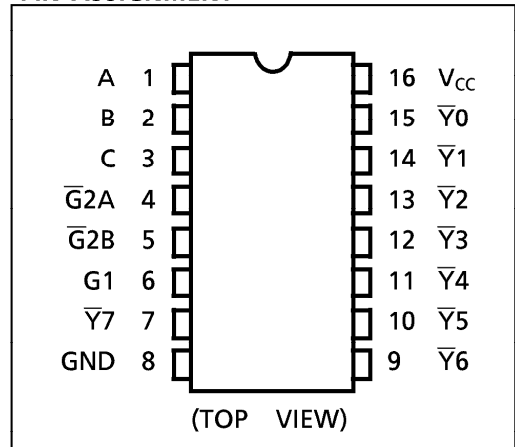
### FEATURES :

- High Speed..... $t_{pd} = 16ns$ (typ.) at  $V_{CC} = 5V$
- Low Power Dissipation..... $I_{CC} = 4\mu A$ (Max.) at  $T_a = 25^\circ C$
- High Noise Immunity..... $V_{NIH} = V_{NIL} = 28\% V_{CC}$  (Min.)
- Output Drive Capability..... 10 LSTTL Loads
- Symmetrical Output Impedance...  $|I_{OH}| = I_{OL} = 4mA$ (Min.)
- Balanced Propagation Delays.....  $t_{pLH} \approx t_{pHL}$
- Wide Operating Voltage Range...  $V_{CC}$  (opr.) = 2V ~ 6V
- Pin and Function Compatible with 74LS138

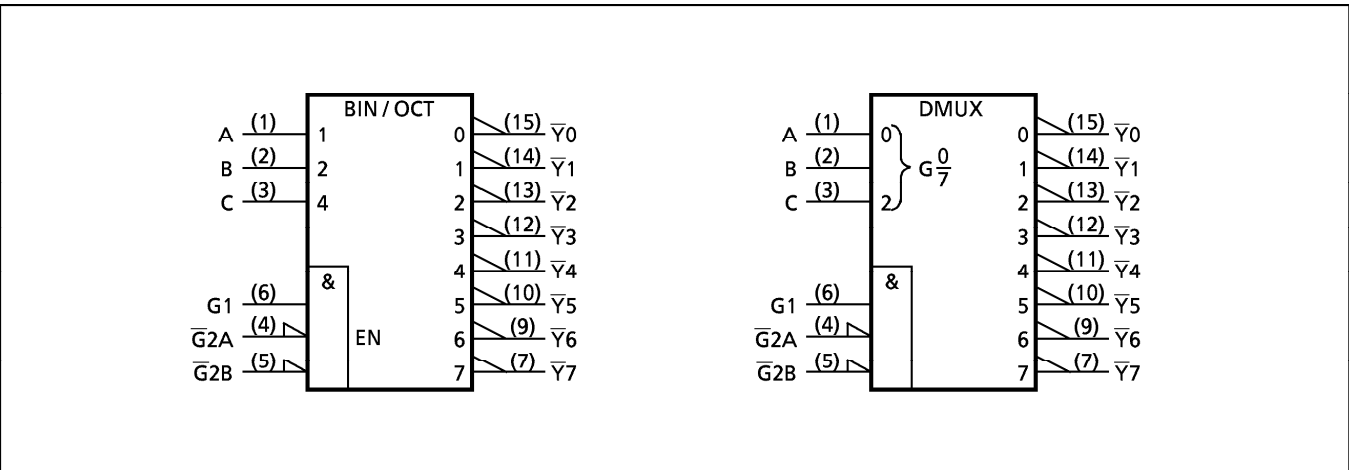
(Note) The JEDEC SOP (FN) is not available in Japan.



### PIN ASSIGNMENT



### IEC LOGIC SYMBOL



961001EBA2

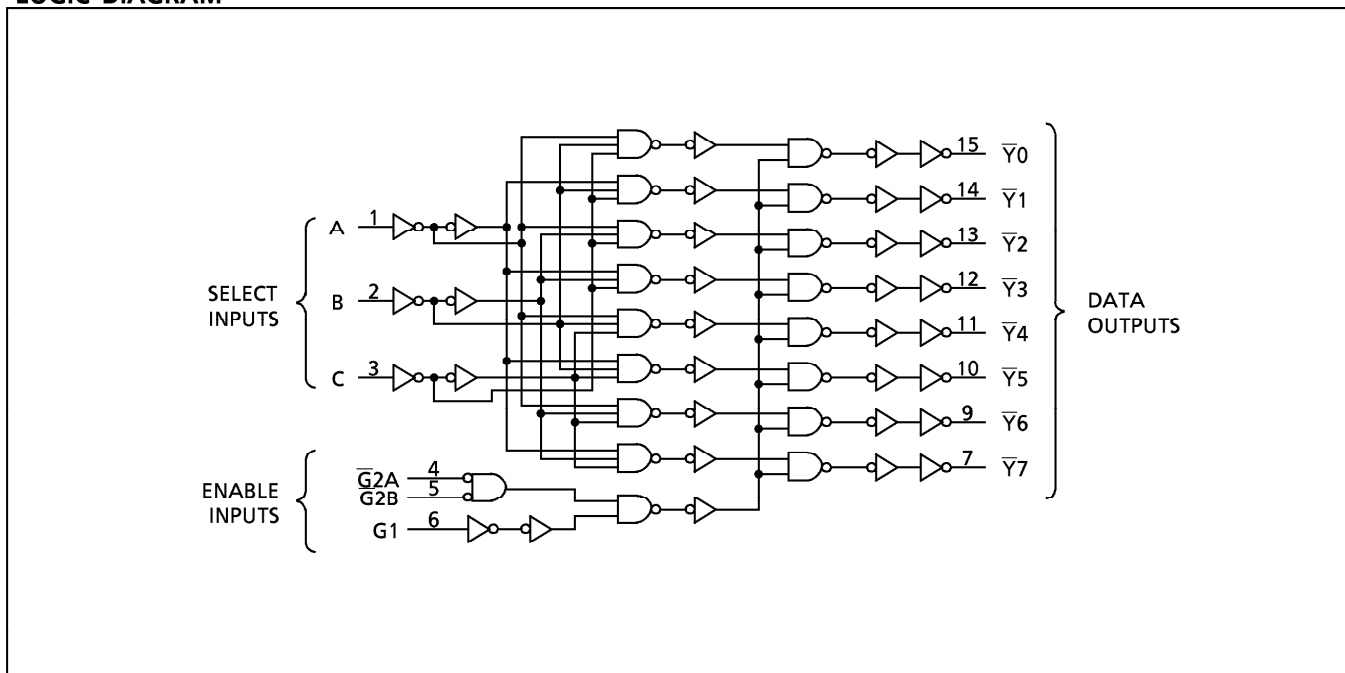
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**TRUTH TABLE**

INPUTS						OUTPUTS								SELECTED OUTPUT
ENABLE			SELECT			$\bar{Y}0$	$\bar{Y}1$	$\bar{Y}2$	$\bar{Y}3$	$\bar{Y}4$	$\bar{Y}5$	$\bar{Y}6$	$\bar{Y}7$	
G1	$\bar{G}2A$	$\bar{G}2B$	C	B	A									
L	X	X	X	X	X	H	H	H	H	H	H	H	H	NONE
X	H	X	X	X	X	H	H	H	H	H	H	H	H	NONE
X	X	H	X	X	X	H	H	H	H	H	H	H	H	NONE
H	L	L	L	L	L	L	H	H	H	H	H	H	H	$\bar{Y}0$
H	L	L	L	L	H	H	L	H	H	H	H	H	H	$\bar{Y}1$
H	L	L	L	H	L	H	H	L	H	H	H	H	H	$\bar{Y}2$
H	L	L	L	H	H	H	H	H	L	H	H	H	H	$\bar{Y}3$
H	L	L	H	L	L	H	H	H	H	L	H	H	H	$\bar{Y}4$
H	L	L	H	L	H	H	H	H	H	H	L	H	H	$\bar{Y}5$
H	L	L	H	H	L	H	H	H	H	H	H	L	H	$\bar{Y}6$
H	L	L	H	H	H	H	H	H	H	H	H	L	H	$\bar{Y}7$

X : Don't Care

**LOGIC DIAGRAM**



961001EBA2'

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**ABSOLUTE MAXIMUM RATINGS**

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	$V_{CC}$	-0.5~7	V
DC Input Voltage	$V_{IN}$	-0.5~ $V_{CC} + 0.5$	V
DC Output Voltage	$V_{OUT}$	-0.5~ $V_{CC} + 0.5$	V
Input Diode Current	$I_{IK}$	± 20	mA
Output Diode Current	$I_{OK}$	± 20	mA
DC Output Current	$I_{OUT}$	± 25	mA
DC $V_{CC}$ / Ground Current	$I_{CC}$	± 50	mA
Power Dissipation	$P_D$	500 (DIP)* / 180 (SOP)	mW
Storage Temperature	$T_{stg}$	-65~150	°C

\*500mW in the range of  $T_a = -40^{\circ}\text{C} \sim 65^{\circ}\text{C}$ . From  $T_a = 65^{\circ}\text{C}$  to  $85^{\circ}\text{C}$  a derating factor of  $-10\text{mW}/^{\circ}\text{C}$  shall be applied until 300mW.

**RECOMMENDED OPERATING CONDITIONS**

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	$V_{CC}$	2~6	V
Input Voltage	$V_{IN}$	0~ $V_{CC}$	V
Output Voltage	$V_{OUT}$	0~ $V_{CC}$	V
Operating Temperature	$T_{opr}$	-40~85	°C
Input Rise and Fall Time	$t_r, t_f$	0~1000 ( $V_{CC} = 2.0\text{V}$ ) 0~500 ( $V_{CC} = 4.5\text{V}$ ) 0~400 ( $V_{CC} = 6.0\text{V}$ )	ns

**DC ELECTRICAL CHARACTERISTICS**

PARAMETER	SYMBOL	TEST CONDITION	$V_{CC}$ (V)	$T_a = 25^{\circ}\text{C}$			$T_a = -40 \sim 85^{\circ}\text{C}$		UNIT					
				MIN.	TYP.	MAX.	MIN.	MAX.						
High - Level Input Voltage	$V_{IH}$		2.0	1.50	—	—	1.50	—	V					
			4.5	3.15	—	—	3.15	—						
			6.0	4.20	—	—	4.20	—						
Low - Level Input Voltage	$V_{IL}$		2.0	—	—	0.50	—	0.50	V					
			4.5	—	—	1.35	—	1.35						
			6.0	—	—	1.80	—	1.80						
High - Level Output Voltage	$V_{OH}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OH} = -20\mu\text{A}$	2.0	1.9	2.0	—	1.9	—	V				
				4.5	4.4	4.5	—	4.4	—					
				6.0	5.9	6.0	—	5.9	—					
Low - Level Output Voltage	$V_{OL}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OL} = 20\mu\text{A}$	2.0	—	0.0	0.1	—	0.1	V				
				4.5	—	0.0	0.1	—	0.1					
				6.0	—	0.0	0.1	—	0.1					
Input Leakage Current	$I_{IN}$	$V_{IN} = V_{CC}$ or GND		6.0	—	—	± 0.1	—	± 1.0	$\mu\text{A}$				
				Quiescent Supply Current	$I_{CC}$	$V_{IN} = V_{CC}$ or GND		6.0	—		—	4.0	—	40.0

**AC ELECTRICAL CHARACTERISTICS (  $C_L = 15\text{pF}$ ,  $V_{CC} = 5\text{V}$ ,  $T_a = 25^\circ\text{C}$ , Input  $t_r = t_f = 6\text{ns}$  )**

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Transition Time	$t_{TLH}$ $t_{THL}$		—	4	8	ns
Propagation Delay Time (A, B, C- $\bar{Y}$ )	$t_{PLH}$ $t_{PHL}$		—	16	26	
Propagation Delay Time (G, $\bar{G}$ - $\bar{Y}$ )	$t_{PLH}$ $t_{PHL}$		—	15	25	

**AC ELECTRICAL CHARACTERISTICS (  $C_L = 50\text{pF}$ , Input  $t_r = t_f = 6\text{ns}$  )**

PARAMETER	SYMBOL	TEST CONDITION	$T_a = 25^\circ\text{C}$			$T_a = -40\sim 85^\circ\text{C}$		UNIT	
			$V_{CC}(\text{V})$	MIN.	TYP.	MAX.	MIN.		MAX.
Output Transition Time	$t_{TLH}$ $t_{THL}$		2.0	—	30	75	—	95	ns
			4.5	—	8	15	—	19	
			6.0	—	7	13	—	16	
Propagation Delay Time (A, B, C- $\bar{Y}$ )	$t_{PLH}$ $t_{PHL}$		2.0	—	70	150	—	190	ns
			4.5	—	19	30	—	38	
			6.0	—	16	26	—	32	
Propagation Delay Time (G, $\bar{G}$ - $\bar{Y}$ )	$t_{PLH}$ $t_{PHL}$		2.0	—	65	145	—	180	ns
			4.5	—	18	29	—	36	
			6.0	—	15	25	—	31	
Input Capacitance	$C_{IN}$		—	5	10	—	10	pF	
Power Dissipation Capacitance	$C_{PD}(1)$		—	47	—	—	—		

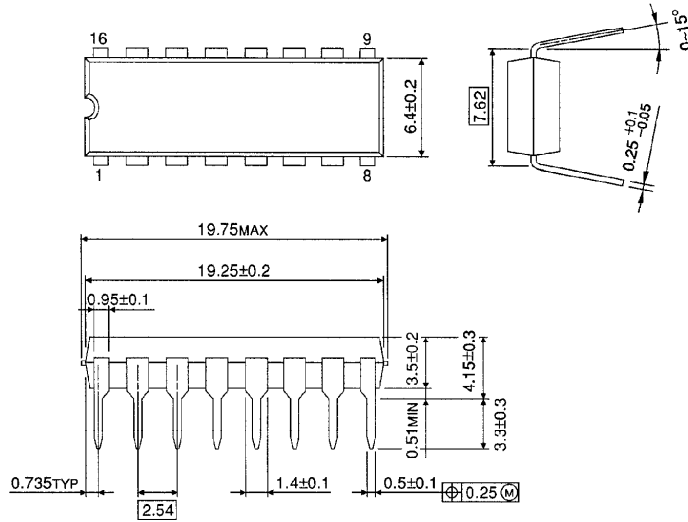
Note (1)  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

$$I_{CC}(\text{opr}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

**DIP 16PIN OUTLINE DRAWING (DIP16-P-300-2.54A)**

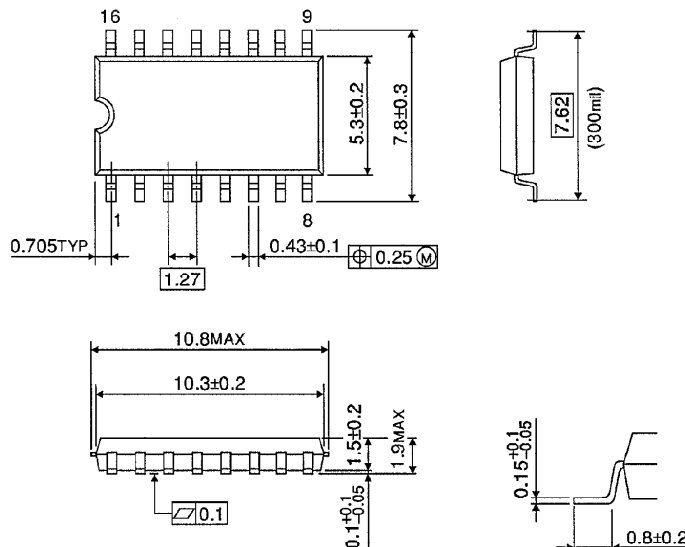
Unit in mm



Weight : 1.00g (Typ.)

**SOP 16PIN (200mil BODY) OUTLINE DRAWING (SOP16-P-300-1.27)**

Unit in mm

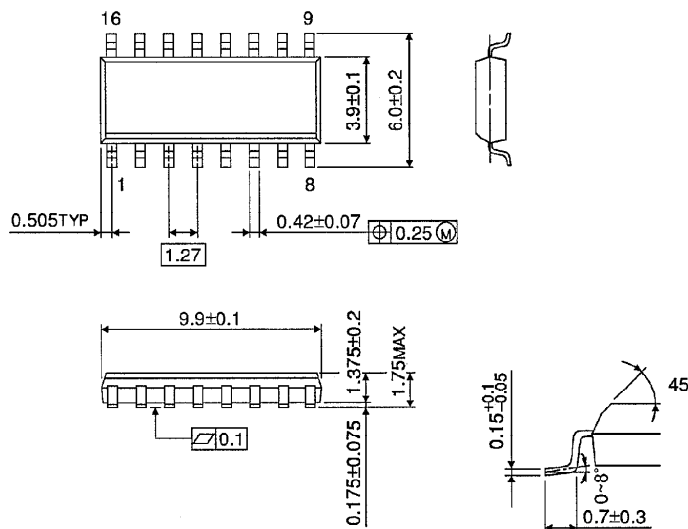


Weight : 0.18g (Typ.)

**SOP 16PIN (150mil BODY) OUTLINE DRAWING (SOL14-P-150 -1.27)**

Unit in mm

(Note) This package is not available in Japan.



Weight : 0.13g (Typ.)